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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



# High hFE Low VCE(sat)

# 2SC4495

Silicon NPN Triple Diffused Planar Transistor

Application : Audio Temperature Compensation and General Purpose

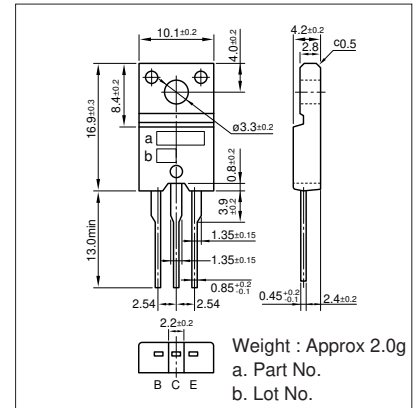
### Absolute maximum ratings (Ta=25°C)

Symbol	Ratings	Unit
V <sub>CB0</sub>	80	V
V <sub>CE0</sub>	50	V
V <sub>EB0</sub>	6	V
I <sub>c</sub>	3	A
I <sub>B</sub>	1	A
P <sub>c</sub>	25(T <sub>c</sub> =25°C)	W
T <sub>j</sub>	150	°C
T <sub>stg</sub>	-55 to +150	°C

### Electrical Characteristics (Ta=25°C)

Symbol	Conditions	Ratings	Unit
I <sub>CB0</sub>	V <sub>CB</sub> =80V	10max	μA
I <sub>EB0</sub>	V <sub>EB</sub> =6V	10max	μA
V <sub>(BR)CEO</sub>	I <sub>c</sub> =25mA	50min	V
h <sub>FE</sub>	V <sub>CE</sub> =4V, I <sub>c</sub> =0.5A	500min	
V <sub>CE(sat)</sub>	I <sub>c</sub> =1A, I <sub>B</sub> =20mA	0.5max	V
f <sub>r</sub>	V <sub>CE</sub> =12V, I <sub>E</sub> =-0.1A	40typ	MHz
COB	V <sub>CB</sub> =10V, f=1MHz	30typ	pF

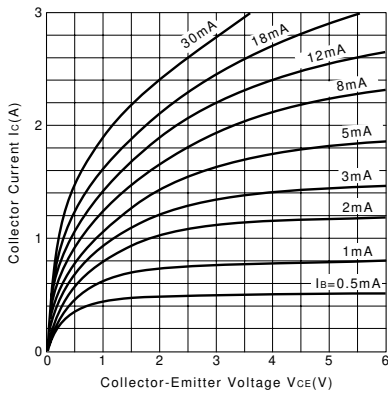
### External Dimensions FM20(TO220F)



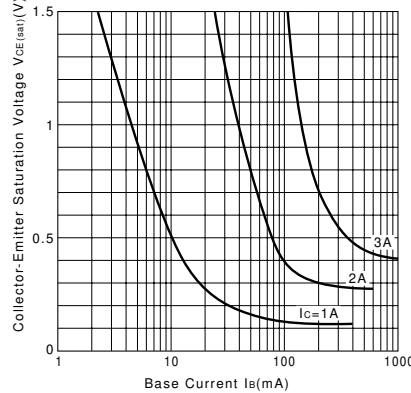
### Typical Switching Characteristics (Common Emitter)

V <sub>CC</sub> (V)	R <sub>L</sub> (Ω)	I <sub>c</sub> (A)	V <sub>BB1</sub> (V)	V <sub>BB2</sub> (V)	I <sub>B1</sub> (mA)	I <sub>B2</sub> (mA)	t <sub>on</sub> (μs)	t <sub>stg</sub> (μs)	t <sub>f</sub> (μs)
20	20	1	10	-5	15	-30	0.45typ	1.60typ	0.85typ

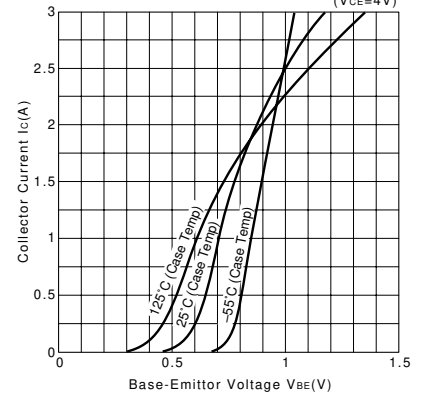
I<sub>c</sub>-V<sub>CE</sub> Characteristics (Typical)



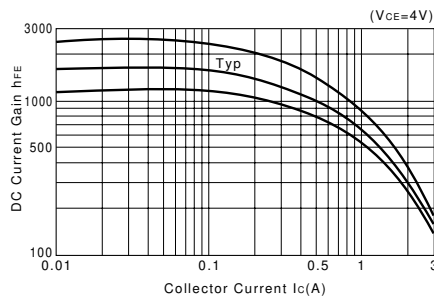
V<sub>CE(sat)</sub>-I<sub>B</sub> Characteristics (Typical)



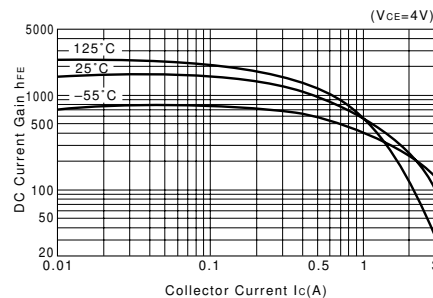
I<sub>c</sub>-V<sub>BE</sub> Temperature Characteristics (Typical)



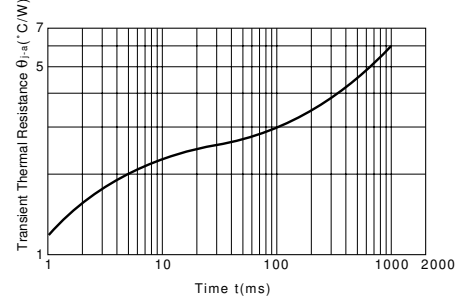
h<sub>FE</sub>-I<sub>c</sub> Characteristics (Typical)



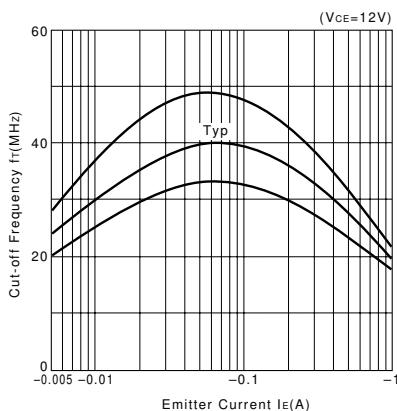
h<sub>FE</sub>-I<sub>c</sub> Temperature Characteristics (Typical)



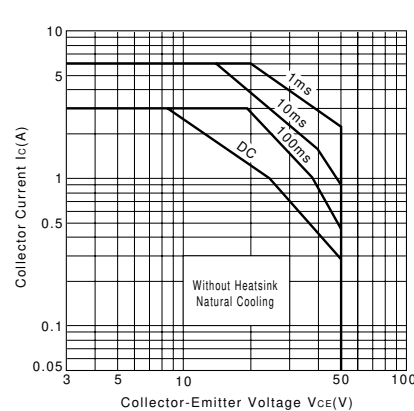
θ<sub>J-a</sub>-t Characteristics



f<sub>r</sub>-I<sub>E</sub> Characteristics (Typical)



Safe Operating Area (Single Pulse)



P<sub>c</sub>-T<sub>a</sub> Derating

